

PRODUCT SUMMARY					
V _{DS} (V)	$R_{DS(on)}(\Omega)$	I _D (A)	Q _g (Typ.)		
- 40	0.0081 at $V_{GS} = -10 \text{ V}$	- 50 ^d	60		
- 40	0.0117 at $V_{GS} = -4.5 \text{ V}$	- 48 ^d	00		

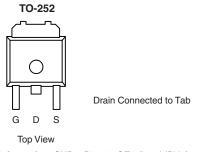
FEATURES

- Halogen-free According to IEC 61249-2-21 **Definition**
- TrenchFET® Power MOSFET
- 100 % R_q and UIS Tested
- Compliant to RoHS Directive 2002/95/EC

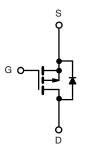


APPLICATIONS

- Power Switch
- Load Switch in High Current Applications
- DC/DC Converters



Ordering Information: SUD50P04-08-GE3 (Lead (Pb)-free and Halogen-free)



P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS T _C = 25 °C, unless otherwise noted						
Parameter	Symbol	Limit	Unit			
Drain-Source Voltage	V _{DS}	- 40	V			
Gate-Source Voltage	V _{GS}	± 20	V			
Continuous Drain Current (T _{.1} = 150 °C)	T _C = 25 °C	1-	- 50 ^d	А		
Continuous Diain Current (1) = 130 C)	T _C = 70 °C	- I _D	- 50 ^d			
Pulsed Drain Current		I _{DM}	- 100	A		
Avalanche Current		I _{AS}	- 46			
Single Avalanche Energy ^a	L = 0.1 mH	E _{AS}	106	mJ		
	T _C = 25 °C	В	73.5 ^b	w		
Maximum Power Dissipation ^a	T _A = 25 °C ^c	$ P_D$	2.5			
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150	°C		

THERMAL RESISTANCE RATINGS					
Parameter	Symbol	Limit	Unit		
Junction-to-Ambient (PCB Mount) ^c	R _{thJA}	50	°C/W		
Junction-to-Case (Drain)	R _{thJC}	1.7	- C/VV		

Notes:

- a. Duty cycle \leq 1 %.
- b. See SOA curve for voltage derating.
- c. When Mounted on 1" square PCB (FR-4 material).
- d. Package limited.

SUD50P04-08 P-Channel 40-V (D-S) MOSFET

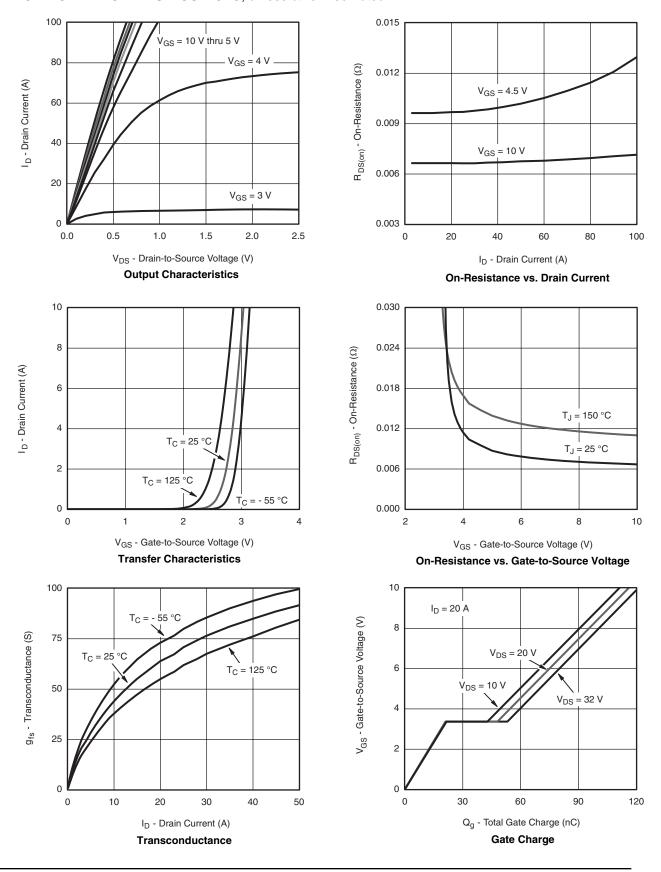
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	V _{DS}	$V_{DS} = 0 \text{ V}, I_{D} = -250 \mu\text{A}$	- 40			_ v	
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	- 1		- 2.5		
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 250	nA	
		V _{DS} = - 40 V, V _{GS} = 0 V			- 1		
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = - 40 V, V _{GS} = 0 V, T _J = 125 °C			- 50	μΑ	
		V _{DS} = - 40 V, V _{GS} = 0 V, T _J = 150 °C			- 250		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \le -10 \text{ V}, V_{GS} = -10 \text{ V}$	- 50			Α	
		V _{GS} = - 10 V, I _D = - 22 A		0.0067	0.0081	Ω	
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = - 4.5 V, I _D = - 19 A		0.0097	0.0117		
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 15 V, I _D = - 22 A		45		S	
Dynamic ^b							
Input Capacitance	C _{iss}	V _{GS} = 0 V, V _{DS} = - 20 V, f = 1 MHz		5380		pF	
Output Capacitance	C _{oss}			570			
Reverse Transfer Capacitance	C _{rss}]		500			
Total Cata Charge ^C	Qg	$V_{DS} = -20 \text{ V}, V_{GS} = -10 \text{ V}, I_{D} = -20 \text{ A}$		106	159	nC	
Total Gate Charge ^c				60	90		
Gate-Source Charge ^c	Q_{gs}	$V_{DS} = -20 \text{ V}, V_{GS} = -4.5 \text{ V}, I_{D} = -20 \text{ A}$		22			
Gate-Drain Charge ^c	Q_{gd}			27			
Gate Resistance	R_g	f = 1 MHz	0.4	1.8	3.6	Ω	
Turn-On Delay Time ^c	t _{d(on)}			15	23		
Rise Time ^c	t _r	V_{DD} = - 20 V, R_L = 2 Ω		12	18	no	
Turn-Off Delay Time ^c	t _{d(off)}	$I_D \cong$ - 10 A, V_{GEN} = - 10 V, R_g = 1 Ω		70	105	- ns	
Fall Time ^c	t _f			18	27		
Drain-Source Body Diode Ratings ar	nd Characteri	stics T _C = 25 °C ^b					
Continuous Current	Is				- 50	Α.	
Pulsed Current	I _{SM}				- 100	Α	
Forward Voltage ^a	V _{SD}	I _F = - 10 A, V _{GS} = 0 V		- 0.8	- 1.5	V	
Reverse Recovery Time	t _{rr}			35	53	ns	
Peak Reverse Recovery Current	I _{RM(REC)}	I _F = - 10 A, dI/dt = 100 A/μs		- 2	- 3	Α	
Reverse Recovery Charge	Q _{rr}	1		33	50	nC	

Notes:

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

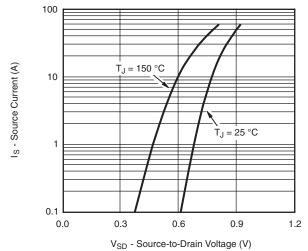
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

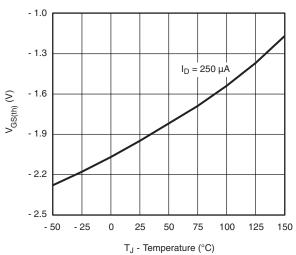




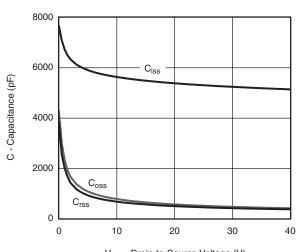
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



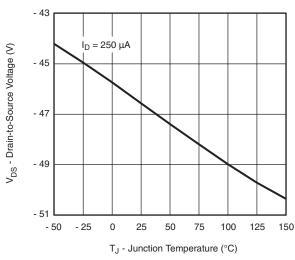
Source-Drain Diode Forward Voltage



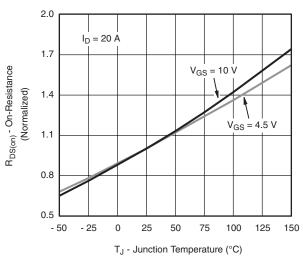
Threshold Voltage



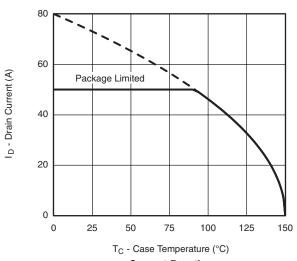
V_{DS} - Drain-to-Source Voltage (V) Capacitance



Drain Source Breakdown vs. Junction Temperature



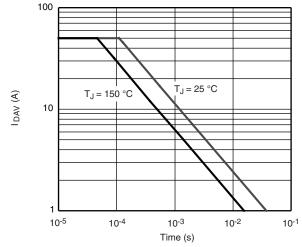
On-Resistance vs. Junction Temperature



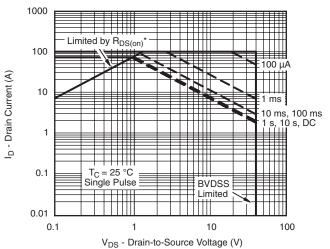
Current Derating

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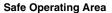
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

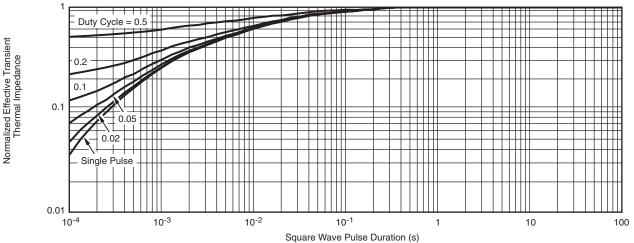


Single Pulse Avalanche Current Capability vs. Time



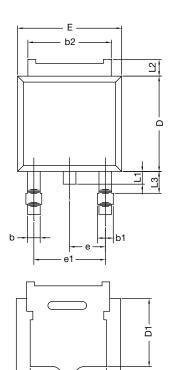
* V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified

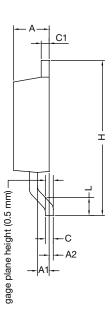




Normalized Thermal Transient Impedance, Junction-to-Case

TO-252AA CASE OUTLINE

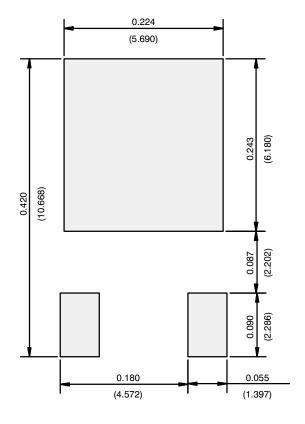




	MILLIMETERS		INCHES	
DIM.	MIN.	MAX.	MIN.	MAX.
Α	2.21	2.38	0.087	0.094
A1	0.89	1.14	0.035	0.045
A2	0.030	0.127	0.001	0.005
b	0.71	0.88	0.028	0.035
b1	0.76	1.14	0.030	0.045
b2	5.23	5.44	0.206	0.214
С	0.46	0.58	0.018	0.023
C1	0.46	0.58	0.018	0.023
D	5.97	6.22	0.235	0.245
D1	4.10	4.45	0.161	0.175
Е	6.48	6.73	0.255	0.265
E1	4.49	5.50	0.177	0.217
е	2.28	BSC	0.090 BSC	
e1	4.57	BSC	0.180 BSC	
Н	9.65	10.41	0.380	0.410
L	1.40	1.78	0.055	0.070
L1	0.64	1.02	0.025	0.040
L2	0.89	1.27	0.035	0.050
L3	1.15	1.52	0.040	0.060
ECN: T11-0110-Rev. L, 18-Apr-11 DWG: 5347				

• Dimension L3 is for reference only.

RECOMMENDED MINIMUM PADS FOR DPAK (TO-252)



Recommended Minimum Pads Dimensions in Inches/(mm)

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SUD50P04-08 P-Channel 40-V (D-S) MOSFET

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